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ATTORNEY DOCKET NO. 10030753-01

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s): Laura Wills Mirkarimi

Serial No.: 10/765647

Examiner: Duy Vu Nguyen Deo

Filing Date: Jan 26, 2004

Group Art Unit: 1765

Title: Method For Etching High Aspect Ratio Features In III-V Based Compounds For Optoelectronic

Devices

COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria VA 22313-1450				
INFORMATION DISCLOSURE STATEMENT				
Sir:				
This Information Disclosure Statement is submitted:				
(a) Under 37 CFR 1.97(b). (Within three months of filing national application; or date of entry of national application; or before mailing date of first Office action on the merits; whichever occurs last).				
(b) Lunder 37 CFR 1.97(c) together with <i>either</i> a: Statement under CFR 1.97(e), or \$\sum_\$ \$180.00 fee under 37 CFR 1.17(p). (After the CFR 1.97(b) time period, but before a final action or notice of allowance, whichever occurs first).				
(c) Under 37 CFR 1.97(d) together with: a Statement under 37 CFR 1.97(e), and \$180.00 fee as set forth in 37 CFR 1.17(p). (After a final action or notice of allowance, whichever occurs first, but before payment of the issue fee).				
The undersigned certifies that: Each item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the statement, or No item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned after making reasonable inquiry, was known to any individual designated in 37 CFR § 1.56(c) more than three months prior to the filing of the Information Disclosure Statement.				
PRIOR APPLICATIONS References identified with an asterisk (*) in the enclosed PTO Form 1449, were disclosed in prior Patent Application No. , filed , now U.S. Patent No. , and, as such, copies thereof are not included pursuant to the provisions of 37 CFR 1.98(d).				
FOREIGN LANGUAGE DOCUMENTS A concise explanation of the relevance of foreign language patents, foreign language publications and other foreign language information listed on PTO form 1449, as presently understood by the individual(s) designated in 37 CFR 1.56(c) most knowledgeable about the content is given on the attached sheet, or where a foreign language patent is cited in a search report or other action by a foreign patent office in a counterpart foreign application, an English language version of the search report or action which indicates the degree of relevance found by the foreign office is listed on form PTO 1449 and is enclosed herewith.				

▼ FEE AUTHORIZATION	
Please charge to Deposit Account 50-1078 the sun of this application, please charge any fees required or credit	n of <u>\$0.00</u> . At any time during the pendenc
pursuant to 37 CFR 1.25.	it any overpayment to Deposit / toodait of 1070
I hereby certify that this correspondence is being deposited with the United States Postal Service as: First Class Mail "Express Mail Post office to Addressee" service under 37 CFR 1.10. Express Mai Label No. Date of Deposit: February 2006 In an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria VA 22313-1450.	Respectfully submitted Laura Wills Mirkarm By Jue gen Krause-Polstorff Attorney/Agent for Applicant(s) Reg. No. 41,127 Date: February 10, 2006 Telephone No. 650 485-5904
OR	
I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.	
Date of Facsimile:	
Typed Name: Linda A. limura	

LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary) ATTORN 10030 APPLICATION FOR Laura FILING II January

ATTORNEY DOCKET NO. 10030753	SERIAL NO. 10/765647	
APPLICANT		
Laura Wills Mirkarimi		
FILING DATE	GROUP	
January 26, 2004	1765	

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

XAMINER * INITIAL	DOCUMENT NUMBER	DATE	NAME
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<u></u> .	<u> </u>	FOREIGN PATENT DOCUM	IENT .

DOCUMENT NUMBER	DATE	NAME	TRANSLATION YES NO
 1 528 592 A2	05/04/2005	EP	

OTHER REFERENCES (in	ncluding Author,	Title, Date,	, Pertinent Pa	ges, etc.)
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Flanders, D. C. et al., "Reactive Ion Etching of Indium Compounds using Iodine C J. Vac. Sci. Technology, B8 (6) Nov/Dec 1990, pp. 1990-1993.	ontaining Plasmas"
Liu, J. Q. et al., "Dry Etching Process in InP Gunn Device Technology Utilizing In (ICP) System", 10th Intern. Conf. on Indium Phosphide and Related Materials, M Japan, pp. 187-190.	

EXAMINER DATE CONSIDERED

^{*} Copies of these references are not enclosed Pursuant to 37 CFR 1.98(d). (See accompanying IDS)